

KBU8A-KBU8M

SINGLE PHASE BRIDGE RECTIFIERS

High-reliability discrete products and engineering services since 1977

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS (T_A = 25°C unless otherwise specified)

Rating	Symbol	KBU8A	KBU8B	KBU8D	KBU8G	KBU8J	KBU8K	KBU8M	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward output rectified current at $T_{A}=50^{\circ}C^{^{(1)}\!_{(2)}}$	I _{F(AV)}				8.0				Amps
Peak forward surge current single sine wave superimposed on rated load	I _{FSM}	300						Amps	
Operating and storage temperature range	T _J , T _{stg}	-50 to +150						°C	
Typical thermal characteristics	R _{ƏJA} R _{ƏJC}	18 ⁽²⁾ 3.0 ⁽³⁾					°C/W		

Note 1: Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw. Note 2: Thermal resistance from junction to ambient with units mounted in free air, no heatsink, PCB at 0.375" lead length and 0.5 x 0.5" copper pads.

Note 3: Thermal resistance from junction to case with units mounted in 3.0 x 3.0 x 0.11" thick aluminum plate heatsink.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Characteristic	Symbol	KBU8A	KBU8B	KBU8D	KBU8G	KBU8J	KBU8K	KBU8M	Units
Maximum instantaneous forward drop per diode @ 8.0A	VF				1.0				Volts
Maximum DC reverse current at rated DC blocking voltage per diode									
T _A = 25°C	IR				10				μA
T _A = 125°C					1.0				mA



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MECHANICAL CHARACTERISTICS

Case	Digi P
Marking	Alpha-numeric
Pin out	See below



	Digi P						
	Inc	hes	Millimeters				
	Min	Max	Min	Max			
A	0.895	0.935	22.700	23.700			
В	-	0.760	-	19.300			
С	0.660	0.700	16.800	17.800			
D	0.165	0.185	4.200	4.700			
F	0.065	0.085	1.700	2.200			
G	0.405	0.455	10.300	11.300			
Н	1.000		25.400				
J	0.200	0.2400	5.080	6.090			
К	0.048	0.052	1.200	1.300			
L	0.180	0.220	4.600	5.600			
М	0.260	0.280	6.600	7,100			
N	0.185	0.205	4.700	5.200			
Ρ	0.140	0.160	3.600	4.100			



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Figure 1. Derating Curve Output Rectified Current



Figure 3. Typical Instantaneous Forward Characteristics Per Diode



Figure 4. Typical Reverse Leakage Characteristics Per Diode

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Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



Figure 5. Typical Junction Capacitance Per Diode